

Use of Sodium Nitrite Auxiliary Electrode for Solid Electrolyte Sensor to Detect Nitrogen Oxides

Sheng YAO, Youichi SHIMIZU, Norio MIURA, and Noboru YAMAZOE*

Department of Materials Science and Technology, Graduate School of Engineering Sciences,
Kyushu University, Kasuga, Fukuoka 816

An Na⁺-conductor (NASICON)-based solid electrolyte device fitted with an NaNO₂ auxiliary electrode showed excellent sensing characteristics to NO and NO₂ in air. The electromotive force, EMF, followed the Nernst's equation for 1 - 800 ppm NO and 0.1-200 ppm NO₂ at temperatures of 150 - 240 °C, the Nernst's slopes indicating one-electron reduction for both gases.

The nitrogen oxides (NO_x: NO and NO₂) generated from automobiles and combustion facilities are serious air pollutants, and their monitoring is urgently needed for the protection of global environments. Many kinds of NO_x sensors have already been reported, such as conductivity type sensors using oxide semiconductors¹⁻⁴⁾ or metal phthalocyanines,⁵⁾ electrochemical sensors using solid electrolytes⁶⁻⁹⁾ and SAW sensors using phthalocyanines.¹⁰⁾ Most of these sensors have aimed at detecting NO₂ out of NO_x, since NO₂ is generally more reactive and easier to detect than NO. For the practical control of combustion exhausts which usually contain far more NO than NO₂, it is more desirable to detect NO. In this respect, only a few sensors such as those based on TiO₂¹⁾ and WO₃⁴⁾ have so far been reported to detect NO. The detection of NO₂, on the other hand, is very important for the environmental monitoring, because NO₂ dominates in the environmental NO_x. For this purpose, sensors should be sensitive enough to detect as dilute as a few tens ppb NO₂. Among various types of NO_x sensors, those using solid electrolytes are of particular interest from the viewpoints of selectivity and simple element structure. We have reported that an electrochemical device using a sodium ion conductor, such as NASICON (Na₃Zr₂Si₂PO₁₂) and β"-alumina, shows rather good sensing characteristics to NO₂ in air when fitted with an auxiliary electrode of metal nitrates.^{8,9)} However, this sensor can not work as an NO sensor as will be shown later. As an approach to a solid electrolyte NO sensor, we have tested the use of NaNO₂ instead of metal nitrates for the auxiliary electrode. It has turned out that the new device not only makes it possible to detect NO but also provide far better sensing characteristics to NO₂ than the previous one, as described below.

The sensor device fabricated is shown in Fig.1. A disc of NASICON, 8 mm in diameter and 0.5 mm thick, was fixed on the end of a quartz glass tube with an inorganic adhesive. The sensing electrode was fabricated by covering the outside surface of the disc with NaNO₂ or NaNO₃ by a melting-quenching method, followed by fixing a gold mesh (100 mesh)

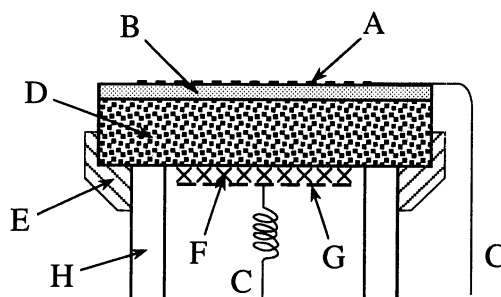


Fig. 1. Structure of NO_x sensor device.
A : Au-mesh, B : NaNO₃ or NaNO₂ electrode, C : Au-wire, D : NASICON,
E : Inorganic adhesive, F : Pt-black,
G : Pt-mesh, H: Quartz glass tube.

on the top of it. The counter electrode (platinum black) was applied on the inside surface of the disc and mechanically contacted to a platinum mesh attached with an Au lead. The counter electrode was always exposed to static atmospheric air. Sensing experiments were conducted in a conventional flow apparatus equipped with heating facilities under atmospheric pressure. Sample gases containing NO or NO₂ were prepared from each parent gas, i.e., NO diluted with nitrogen or NO₂ diluted with air, by mixing it with synthetic air and/or pure oxygen. The oxygen concentration of the sample gases was maintained at a constant of 21 vol%. The sensor response, EMF, was measured with a digital electrometer (Advantest, TR 8552) at a total flow rate of 100 cm³/min.

The sensing characteristics of the device fitted with an NaNO₃ electrode are shown in Figs. 2 and 3. As reported previously, the device responded rather well to switching between synthetic air (0 ppm NO₂) and 1 or 20 ppm NO₂ at 150 °C (Fig. 2(a)), the times for 90% response and 90% recovery being ca. 2 min and 14 min, respectively. The EMF responses were linear to the logarithm of the NO₂ concentration (Fig. 3(a)), with a Nernst's slope of 84 mV/decade, or $n=1.0$, where n is the number of electrons involved in the electrode reaction per NO₂ molecule. The device also responded to NO as shown in Fig. 2(b), but the EMF responses were not well correlated with the NO concentration as shown in Fig. 3(b). Possibly NO was partly oxidized to NO₂ on the electrode and the produced NO₂ was responsible for the EMF response. Anyway this device could not be used as an NO sensor.

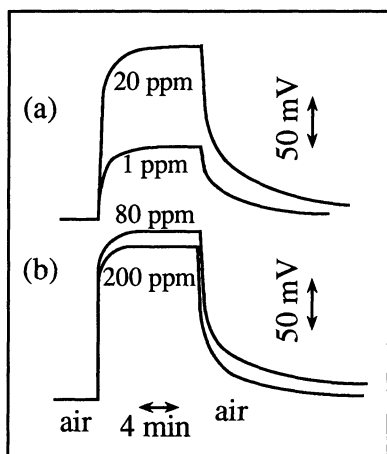


Fig. 2. Response transients of the device fitted with NaNO₃ electrode at 150 °C. (a), NO₂; (b), NO.

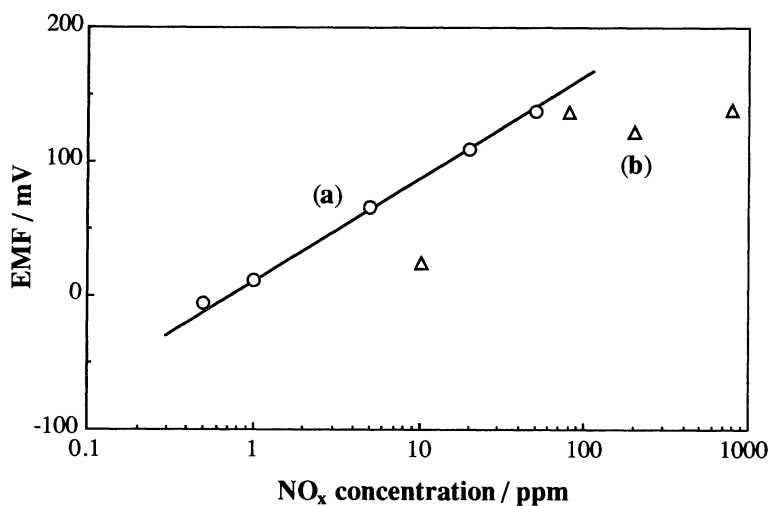


Fig. 3. EMF vs. NO₂ or NO concentration at 150 °C for the device fitted with NaNO₃ electrode. (a): NO₂; (b): NO.

The sensing properties of the new device using NaNO₂ are shown in Figs. 4 and 5. It could respond to both NO₂ and NO (Fig. 4). The EMF response followed the Nernst's equation for both gases (Fig. 5). The Nernst's slope of 84 mV/decade for NO was in agreement with $n = 1$. Although the slope for NO₂ gave $n = 1.1$ in this particular experiment, the n values for NO₂ were very close to 1.0 in most cases. These results indicate that the use of the NaNO₂ auxiliary electrode enables one to fabricate an NO sensor unlike the case of the NaNO₃ electrode. In addition, the same device can also work as an excellent NO₂ sensor.

The use of the NaNO₂ electrode was found to also bring about other advantageous effects. First, the rates of response to NO and NO₂ were far higher than those observed with the NaNO₃ electrode. The 90% response times on exposure to NO and NO₂ at 150 °C were as short as 8 s when the gas concentrations were 10 ppm and above, while the recovery rates on turning-off the gases were rather slow at the same temperature. The recovery rates increased drastically with increasing operation temperature, to give the 90% recovery times of ca. 2 min for

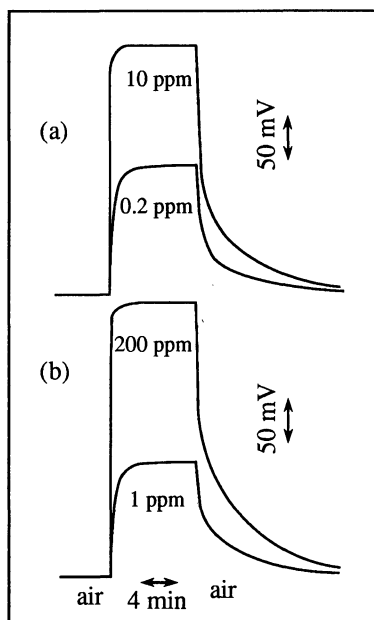


Fig. 4. Response transients of the device fitted with NaNO_2 electrode at 150°C . (a), NO_2 ; (b), NO .

1 - 200 ppm NO and 1 - 100 ppm NO_2 at 180°C (Fig. 6(a)). The rates increased further at higher temperature, as seen from the response transients at 225°C (Fig. 6(b)). No such quick response and recovery could be observed with the NaNO_3 electrode even when temperature was raised.

Second, for a fixed concentration of NO or NO_2 , the increment of EMF on switching from air to the sample gas, i.e., the difference in EMF between the air level and the stationary gas level, was much

larger with the NaNO_2 electrode than with NaNO_3 . This is apparent when one compares the response transients in Fig. 4 (NaNO_2) with those in Fig. 2 (NaNO_3). At 150°C the air levels were ca. -300 mV and ca. -60 mV , while the stationary gas levels to 1 ppm NO_2 , for example, were -95 mV and 11 mV , for the NaNO_2 and NaNO_3 electrodes, respectively. With such a large increment of EMF, the device using NaNO_2 has a potential capability of sensing very dilute NO and NO_2 . In fact, the increment of EMF was as large as ca. 120 mV to 100 ppb NO_2 at 150°C . Combined with the rapidly responding nature just mentioned, the device could respond to as dilute as 50 ppb NO_2 at 180°C (Fig. 6(a)). It seems possible to measure directly the environmental NO_2 with this device.

A problem about the NaNO_2 electrode seems to be its chemical stability to oxidation to NaNO_3 . It was found that a small amount of NaNO_3 phase was formed when NaNO_2 was heated above its melting point (270°C) for 30 min in air. Probably because of such oxidation, the sensing performances of the device for NO and NO_2 began to be unstable at higher temperatures than 240°C .

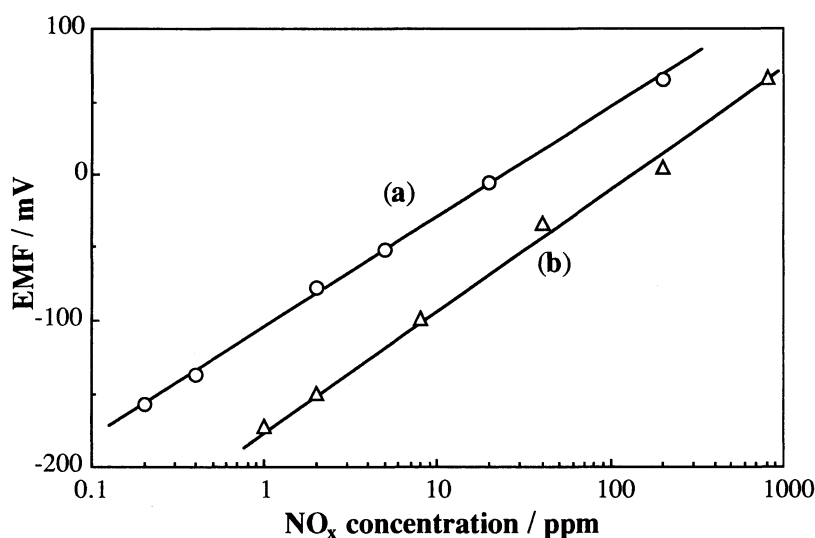


Fig. 5. EMF vs. NO_2 or NO concentration at 150°C for the device fitted with NaNO_2 electrode. (a): NO_2 ; (b): NO .

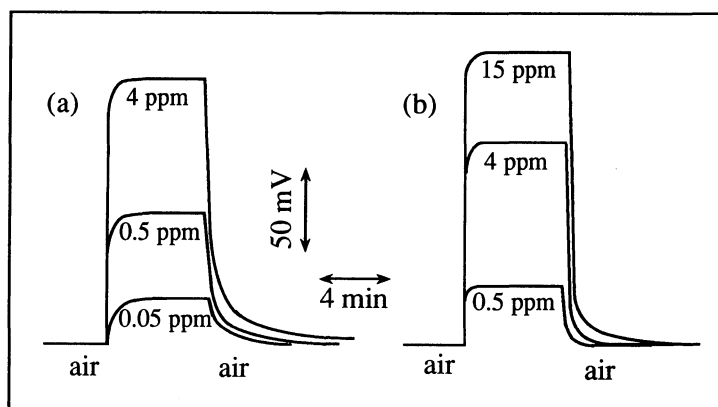
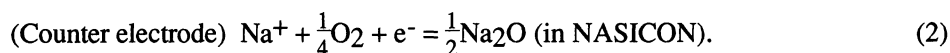
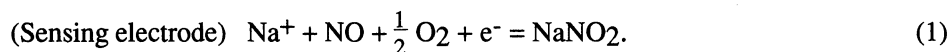


Fig. 6. NO_2 response transients of the device fitted with NaNO_2 electrode at 180°C (a) and 225°C (b).

The sensing mechanisms of the present electrochemical device are still under investigation. The device is expressed as follows,

air, Pt / NASICON / NaNO₂, Au, NO_x + air.
(counter electrode) (Na⁺ conductor) (sensing electrode)

We have previously postulated the NO₂ sensing mechanism of the NaNO₃-fitted device.^{8,9} It is possible to postulate a similar mechanism for NO sensing by the present device. The following electrochemical reactions are assumed to take place on the sensing and counter electrodes.



The overall chemical reaction is then reduced to



Under the conditions of constant activities of NaNO₂ and Na₂O and a constant oxygen partial pressure, EMF is expressed as

$$E = E^\circ + (RT/F) \ln P(\text{NO}), \quad (4)$$

where P(NO) is the partial pressure of NO, E^o is a constant, and RT and F have their conventional meanings. This mechanism accounts for the observed Nernst's slope for NO (n = 1).

There are two possibilities for the NO₂ sensing mechanism. The first one is to assume that NO₂ undergoes the sensing electrode reaction,



Combining Eq. 5 with Eq. 2, one obtains an expression of EMF similar to Eq. 4. The second one is to assume that the partial formation of NaNO₃ from NaNO₂ allows the same NO₂ sensing mechanism to operate as postulated for the NaNO₃ electrode. It is not clear at present which mechanism dominates.

In conclusion, the NASICON-based solid electrolyte device fitted with an NaNO₂ auxiliary electrode exhibits fascinating characteristics for sensing NO and NO₂. Elucidation of the sensing mechanisms as well as the method to stabilize the nitrite electrode appear to be important subjects of further investigations.

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References

- 1) K. Satake, A. Kobayashi, T. Inoue, T. Nakahara, and T. Takeuchi, *Proc. 3rd Int. Meet. on Chem. Sens.*, **1990**, 334.
- 2) G. Sberveglieri, S. Groppelli, P. Nelli, V. Lanto, H. Torvela, P. Romppainen, and P. Leppavuori, *Sens. Actuators*, **B1**, 79 (1990).
- 3) T. Ishihara, K. Shiokawa, K. Eguchi, and H. Arai, *Sens. Actuators*, **19**, 259 (1989).
- 4) M. Akiyama, J. Tamaki, N. Miura, and N. Yamazoe, *Chem. Lett.*, **1991**, 1611 (1991).
- 5) T. A. Jones, B. Bott, and S. C. Thorpe, *Sens. Actuators*, **17**, 467 (1989).
- 6) M. Gauthier and A. Chamberland, *J. Electrochem. Soc.*, **124**, 1579 (1977).
- 7) G. Hötzel and W. Weppner, *Sens. Actuators*, **12**, 449 (1987).
- 8) Y. Shimizu, Y. Okamoto, S. Yao, N. Miura, and N. Yamazoe, *Denki Kagaku*, **59**, 465 (1991).
- 9) S. Yao, Y. Shimizu, N. Miura, and N. Yamazoe, *Technical Digest of 10th Sens. Symp.*, **1991**, 57.
- 10) M. S. Nieuwenhuizen and A.J. Nederlof, *Sens. Actuators*, **19**, 385 (1989).

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